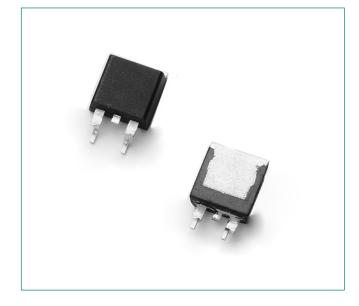


Surface Mount - 400V - 600V > MCR716, MCR718

MCR716, MCR718



Description

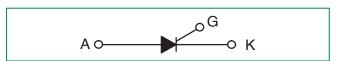
Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

P0

Features

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings: Human Body Model, 3B > 8000 V Machine Model, C > 400 V
- Pb-Free Packages are Available

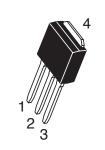
Functional Diagram













Surface Mount - 400V - 600V > MCR716, MCR718

Maximum Ratings ($T_{J} = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (T _J =– 40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open) MCR716 MCR718	V _{drm} , V _{rrm}	400 600	V
On-State RMS Current (All Conduction Angles; $T_c = 90^{\circ}C$)	I _{T (RMS)}	4.0	А
Average On–State Current (180° Conduction Angles; $T_c = 90$ °C)	I _{T(AV)}	2.6	A
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 110°C)	I _{TSM}	25	A
Circuit Fusing Consideration (t = 8.3 ms)	l²t	2.6	A ² sec
Forward Peak Gate Power (Pulse Width \leq 10. $\mu sec, T_c$ = 90°C)	P _{GM}	0.5	W
Forward Average Gate Power (t = 8.3 msec, $T_c = 90^{\circ}C$)	P _{gm (AV)}	0.1	W
Forward Peak Gate Current (Pulse Width $\leq 1.0 \ \mu sec$, T _c = 90°C)	I _{GM}	0.2	A
Operating Junction Temperature Range	TJ	-40 to +110	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics Rating Symbol Value Unit Thermal Resistance, Junction-to-Case R_{BJC} 3.0 °C/W Thermal Resistance, Junction-to-Ambient (Note 2) R_{BJA} 80 °C/W Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds T_L 260 °C



Surface Mount - 400V - 600V > MCR716, MCR718

Electrical Characteristics \cdot **OFF** (T₁ = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current	$T_J = 25^{\circ}C$	I _{DRM} ,	-	-	10	uA
(Note 3) (V _{AK} = Rated V _{DRM} or V _{RRM'} R _{GK} = 1.0 kΩ	T _J = 110°C	I RRM	-	-	200	μΑ

Electrical Characteristics - **ON** ($T_1 = 25^{\circ}C$ unless otherwise noted)

Characteristic			Symbol	Min	Тур	Max	Unit
Peak Reverse Gate Blocking Voltage (I $_{\rm gR}$ = 10 $\mu A)$			V _{grm}	10	12.5	18	V
Peak Reverse Gate Blocking Current (V $_{\rm GR}$ = 10 V)			I _{rgm}	-	-	1.2	μA
		(I _{TM} = 5.0 A Peak)	V	-	1.3	1.5	V
Peak Forward On-State Voltage (Note 4)		(I _{TM} = 8.2 A Peak)	V _{TM}	-	1.5	2.2	
Gate Trigger Current (Continuous dc) (Note 5)		(T _J = 25°C)		1.0	25	75	μA
$(V_{AK} = 12 \text{ Vdc}, R_{L} = 30 \Omega)$		$(T_{J} = -40^{\circ}C)$	I _{GT}	_	-	300	
		(T _J = 25°C)		0.3	0.55	0.8	
Gate Trigger Voltage (Continuous dc) ($V_p = 12 V_{pc'}, R_1 = 30 \Omega$) (Note 5)		$(T_{J} = -40^{\circ}C)$	V _{gt}	-	-	1.0	V
$(v_{\rm D} = 12, v_{\rm DC}, 11 = 00, 10, (1000, 0)$		(T _J = 110°C)		0.2	-	_	
Holding Current (V _D = 12 V, Initiating Current = 200 mA, R _{GK} = 1 kΩ)		(T _J = 25°C)	I _H	0.4	1.0	5.0	
		(T _J = -40°C)		-	-	10	- mA
Latching Current (V	$I_{\rm p} = 12 V_{\rm pc'} I_{\rm g} =$	= 2.0 mA,T _c = 25°C)	I _L	_	-	5.0	
$(V_{_{D}} = 12 V_{_{DC}}, I_{_{G}} = 2.0 \text{ mA}, T_{_{C}} =$		= 2.0 mA,T _c = -40°C)		_	-	10	mA
Total Turn–On Time (Source Voltage = 12 V, $R_s = 6.0 \text{ k}\Omega$, $I_T = 8 \text{ A(pk)}$, R_G (VD = Rated V _{DRM} , Rise Time = 20 ns, Pulse Width =			tgt	-	2.0	5.0	μs

Dynamic Characteristics

	Symbol				
Characteristic		Min	Тур	Max	Unit
Critical Rate of Rise of Off–State Voltage ($V_D = 0.67 \text{ X}$ Rated V_{DRM} , Exponential Waveform, $R_{GK} = 1.0 \text{ kQ}$, TJ = 110°C)	dv/dt	5.0	10	_	V/µs
Critical Rate of Rise of On-State Current (IPK = 50 A, Pw = 40 sec, diG/dt = 1 A/sec, Igt = 50 mA	di/dt	_	-	100	Aµs

2. Case 369C, when surface mounted on minimum recommended pad size.

3. Ratings apply for negative gate voltage or RGK = 1.0 kQ. Devices shall not have a positive gate voltage concurrently with a negative voltage on the anode. Devices should not be tested with a constant current source for forward and reverse blocking capability such that the voltage applied exceeds the rated blocking voltage.

4. Pulse Test; Pulse Width ≤ 2.0 msec, Duty Cycle $\leq 2\,\%$.

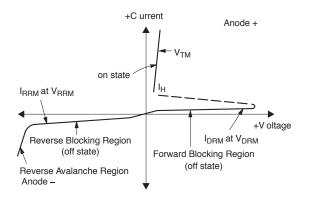
5. RGK current not included in measurements.



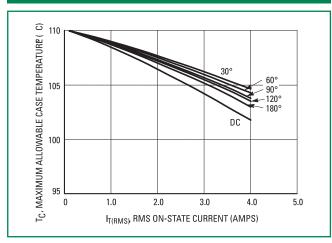
Surface Mount – 400V - 600V > MCR716, MCR718

Voltage Current Characteristic of SCR

Symbol	Parameter	
V _{drm}	Peak Repetitive Forward Off State Voltage	
I _{DRM}	Peak Forward Blocking Current	
V _{RRM}	Peak Repetitive Reverse Off State Voltage	
I _{RRM}	Peak Reverse Blocking Current	
V _{TM}	Maximum On State Voltage	
I _H	Holding Current	







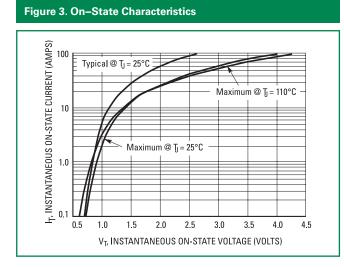


Figure 2. On-State Power Dissipation

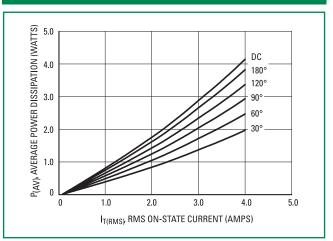
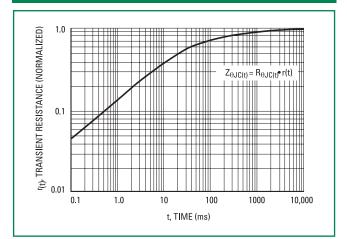


Figure 4. Transient Thermal Response





Surface Mount – 400V - 600V > MCR716, MCR718

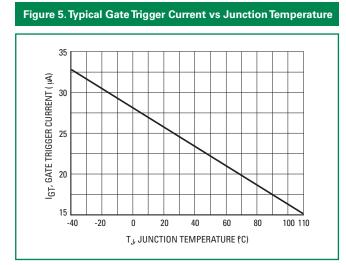


Figure 6. Typical Gate Trigger Voltage vs Junction Temperature

Figure 7. Typical Holding Current vs Junction Temperature

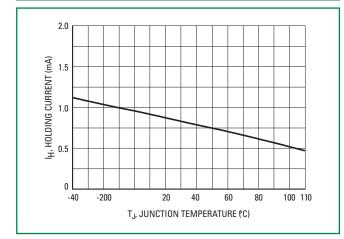
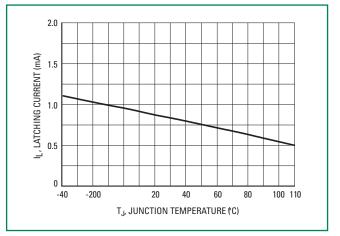


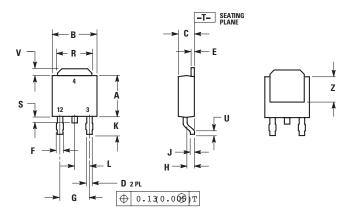
Figure 8. Typical Latching Current vs Junction Temperature





Surface Mount – 400V - 600V > MCR716, MCR718

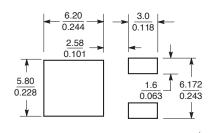
Dimensions



D .	Inches		Millimeters		
Dim	Min	Max	Min	Max	
А	0.235	0.245	5.97	6.22	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
E	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.180 BSC		4.58 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.102	0.114	2.60	2.89	
L	0.090 BSC		BSC 2.29 BSC		
R	0.180	0.215	4.57	5.45	
S	0.025	0.040	0.63	1.01	
U	0.020		0.51		
V	0.035	0.050	0.89	1.27	
Z	0.155		3.93		

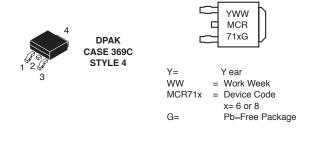
DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.

Soldering Footprint



SCALE 3:1 (mm/inches)

Part Marking System



Pin Assignment	
1	Cathode
2	Anode
3	Gate
4	Anode

Ordering Information Shipping Device Package MCR716T4 DPAK DPAK MCR716T4G (Pb-Free) 2500/ Tape & Reel MCR718T4 DPAK DPAK MCR718T4G (Pb-Free)

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